

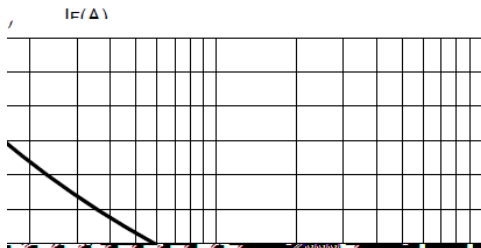
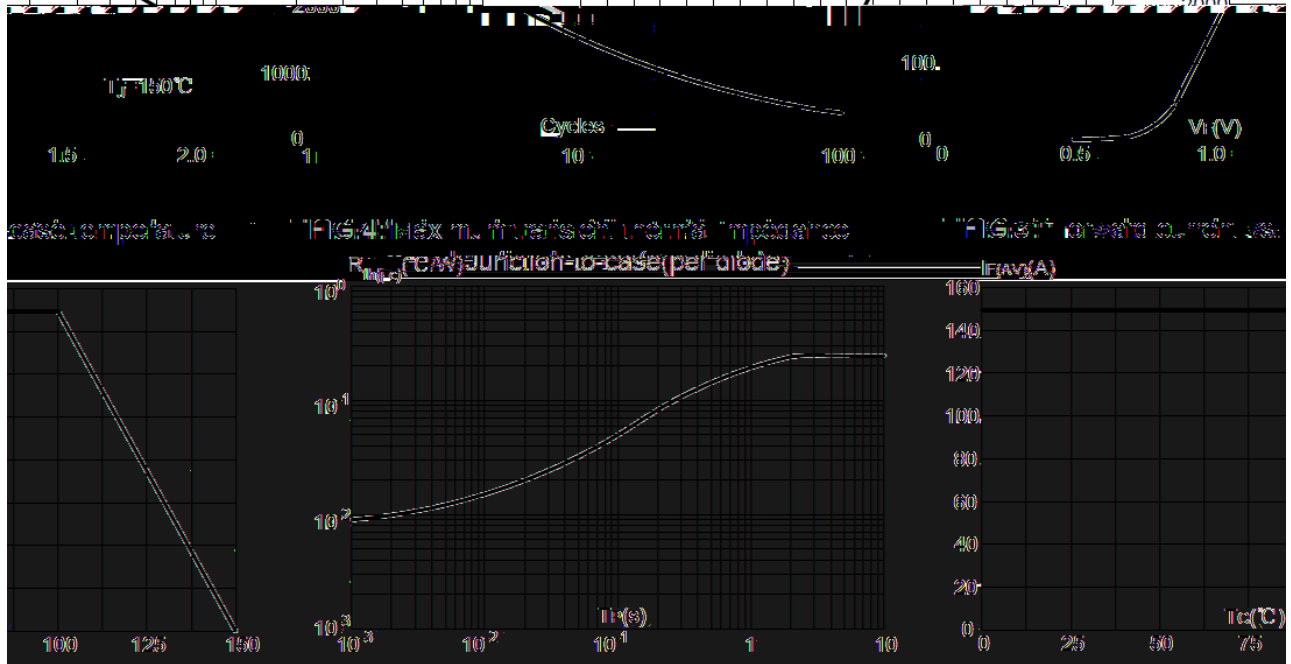
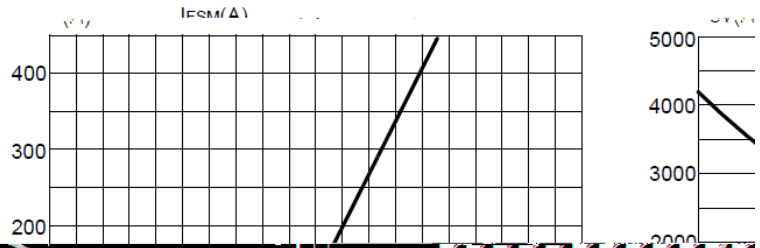


JMD150KD16T1W

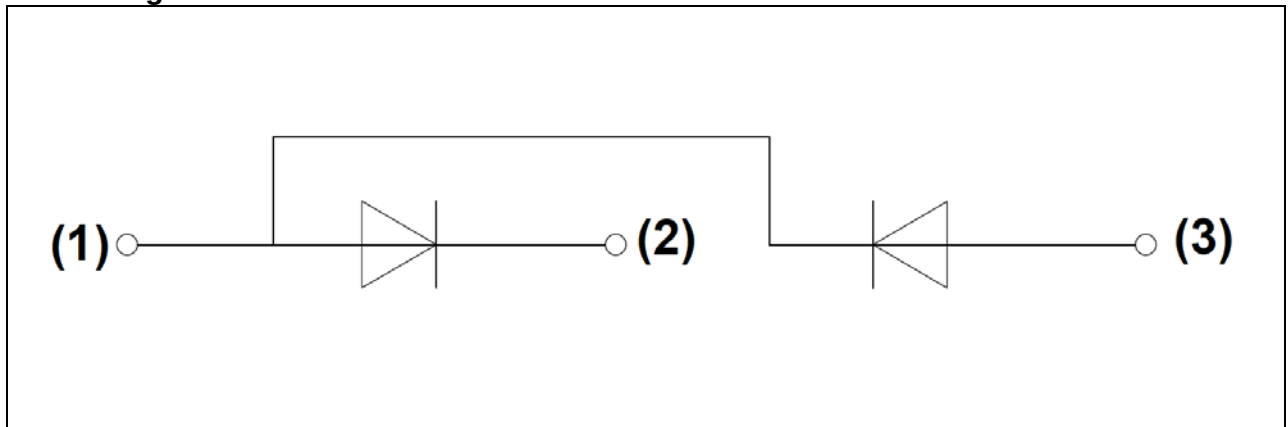
**Electrical Characteristics** (@ $T_C = 25^\circ\text{C}$ unless otherwise specified)

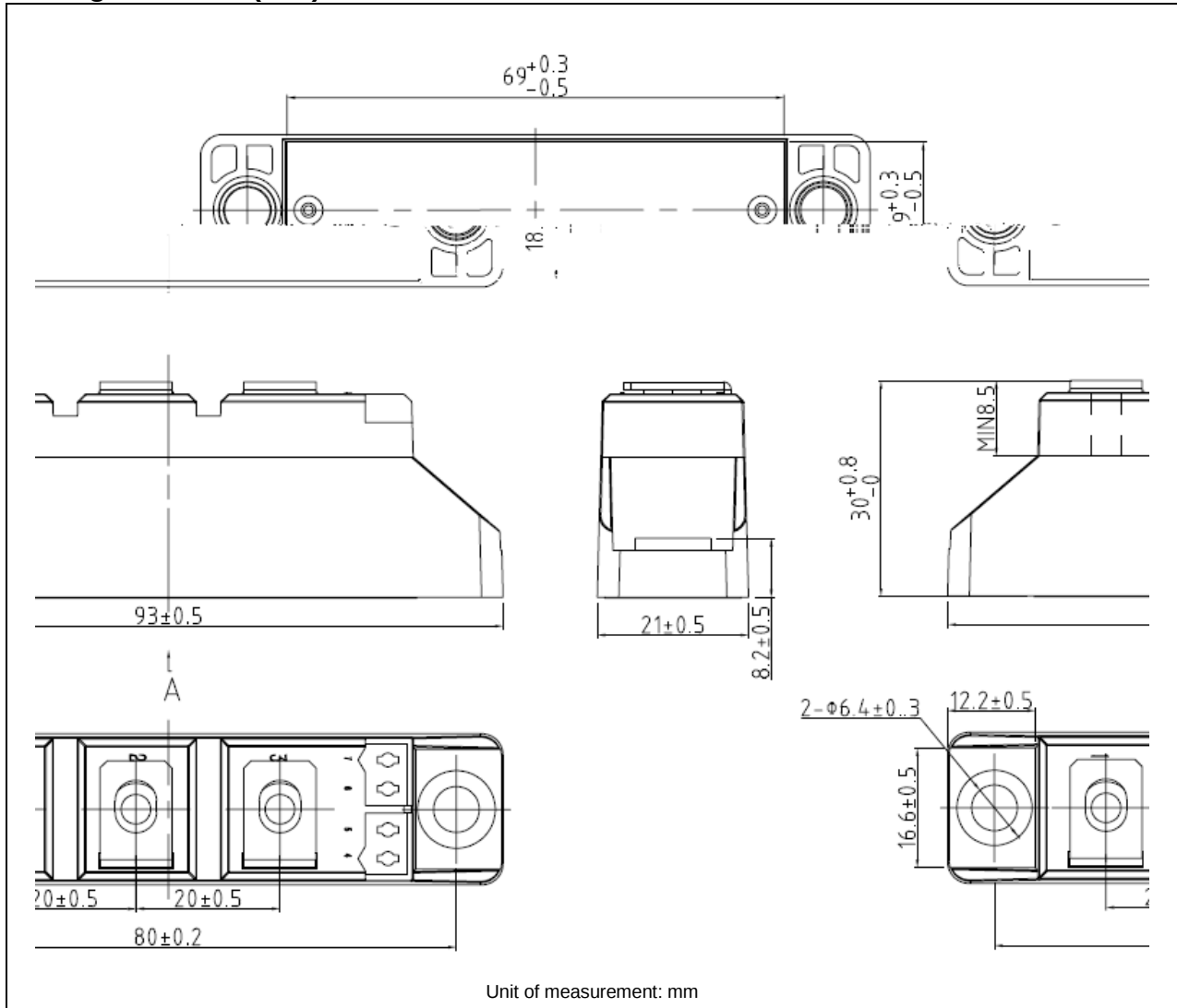
Parameter	Conditions	Symbol	Values			Unit
			Min.	Typ.	Max.	
Peak forward voltage	$I_F=450\text{A}$, $t_P=380\mu\text{s}$	V_{FM}			1.60	V

Typical Electrical & Thermal Characteristics

FIG.1: Forward characteristics(per diode)

FIG.2: Peak on-state surge current


Circuit Diagram



Package Outlines (mm)




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